Supporting Information

Synthesis of magnetofluorescence Gd-doped CuInS₂/ZnS quantum dots with enhanced longitudinal relaxivity

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Figure S1. (a) Absorbance and (b) fluorescence emission spectra of Gd:CIS *q*-dots prepared under different Cu:Gd molar ratios, keeping the other variables constant



Figure S2. EDS analysis data of the as-prepared (a) Gd:CIS core and (b) Gd:CIS/ZnS core/shell *q*-dots. The Au signals are owing to the Au TEM grid.



Figure S3. Representative XRD patterns of the as-prepared Gd:CIS core and Gd:CIS/ZnS core/shell q-dots. The XRD line patterns (bottom) correspond to bulk chalcopyrite CuInS₂ (JCPDS 85-1575) and bulk zinc blende ZnS (JCPDS 80-0020), respectively.



Figure S4. (a) T_1 -weighted images of Gd-DTPA containing various Gd concentrations. (b) Plots of inverse relaxation times $(1/T_1)$ versus Gd concentration of Gd-DTPA. The slope corresponds to the specific relaxivity value (r_1) .